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PATENT
Attorney's Doc. No. 4591-340
Client Ref. No. IE12301-US

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent No.:	US 6,967,860 B2
Inventor:	Choi et al.
Issued:	November 22, 2005

For: FERROELECTRIC MEMORY DEVICE AND CONTROL METHOD THEREOF

Ser. No.:	10/683,663	Filed:	October 9, 2003
Group Art Unit:	2824	Examiner:	Tuan T. Nguyen

TRANSMITTAL LETTER

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Enclosed for filing are the following:

☒ Request for Certificate of Correction
☒ Certificate of Correction Form PTO 1050 (in duplicate)
☒ Return postcard
☒ Any deficiency or overpayment should be charged or credited to deposit account number 13-1703.

Respectfully submitted,

MARGER JOHNSON & McCOLLOM, P.C.

Graciela G. Cowger
Reg. No. 42,444

Certificate of Correction
NOV 07 2006

MARGER JOHNSON & McCOLLOM, P.C.
210 SW Morrison Street, Suite 400
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503-222-3613
Customer No. 20575

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450
Date: November 1, 2006

Kelly Andrews

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REQUEST FOR CERTIFICATE OF CORRECTION

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Upon comparison of the above-identified original Letters Patent with applicant's copy of the application therefore, the following error in the original Letters Patent has been noted:

On the Cover Page, under ABSTRACT, please replace "A ferroelectric random access memory device including a pulse generator circuit capable of generating a pulse signal in response to an address transition." with --A ferroelectric random access memory device according to the present invention includes a pulse generator circuit capable of generating a pulse signal in response to an address transition.--

Applicant respectfully requests that a Certificate of Correction calling attention to the above error be issued pursuant to Rule 322 of the Patent Office and Title 35, United States Code, Section 254. Two copies of a Certificate of Correction form are enclosed.

Respectfully submitted,

MARGER JOHNSON & McCOLLOM, P.C.

Graciela G. Cowger
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Kelly Andrews

PTO/SB/44 (02-01)
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UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO	:	US 6,967,860 B2
DATED	:	November 22, 2005
INVENTOR(S)	:	Choi et al.

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

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MAILING ADDRESS OF SENDER:
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PATENT NO: US 6,967,860 B2

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